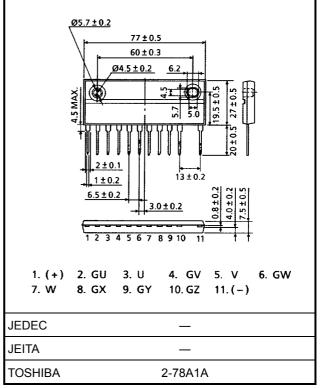
TOSHIBA TOSHIBA GTR Module Silicon N Channel IGBT

# MP6759

### Motor Control Applications High Power Switching Applications

- The electrodes are isolated from case.
- 6 IGBTs are built into 1 package.
- Enhancement-mode
- Low saturation voltage : VCE (sat) = 2.7 V (max) (IC = 10 A)
- High speed:  $t_f = 0.35 \ \mu s \ (max) \ (I_C = 10 \ A)$



Weight: 44 g (typ.)

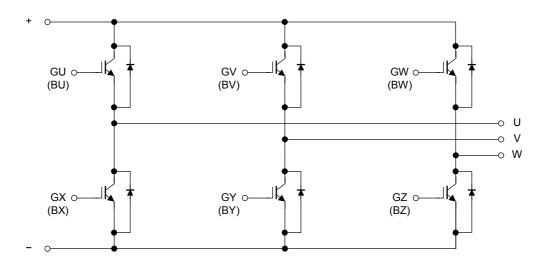
Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	600	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	Ι <sub>C</sub>	10	A	
	1 ms	I <sub>CP</sub>	20		
Forward current	DC	١ <sub>F</sub>	10	A	
	1 ms	I <sub>FM</sub>	20		
Collector power dissipation		P	40	W	
(Tc = 25°C)		PC	40		
Junction temperature		Тj	150	°C	
Storage temperature range		T <sub>stg</sub>	-40 to 125	°C	
Isolation voltage		Maria	2500	) V	
		V <sub>Isol</sub>	(AC 1 minute)	V	
Screw torque		—	1.5	N∙m	

#### Maximum Ratings (Ta = 25°C)

Unit: mm

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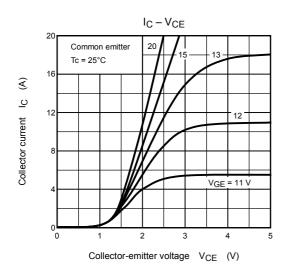
## **Equivalent Circuit**

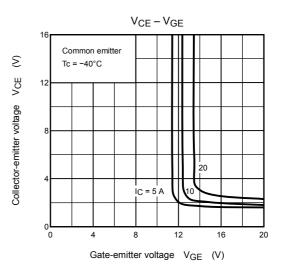


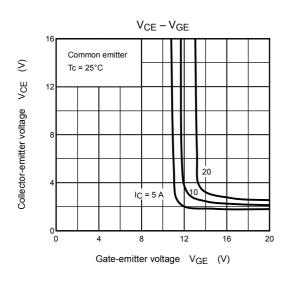
## Electrical Characteristics (Ta = 25°C)

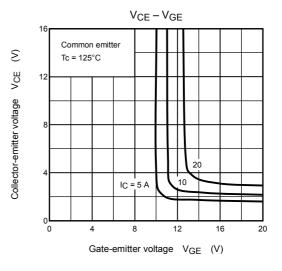
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		IGES	V <sub>GE</sub> = ±20 V, V <sub>CE</sub> = 0 V		—	±200	nA
Collector cut-off current		ICES	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0 V		_	1	mA
Gate-emitter cut-off voltage Vo		V <sub>GE (off)</sub>	I <sub>C</sub> = 1 mA, V <sub>CE</sub> = 5 V	5	_	8	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 10 A, V <sub>GE</sub> = 15 V		2.1	2.7	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10 V, V <sub>GE</sub> = 0 V, f = 1 MHz	_	720	_	pF
Switching time	Rise time	tr	$ \begin{array}{c} 100 \Omega \\ 0 V \\ -15 V \\ -15 V \\ 300 V \end{array} $	_	0.3	_	μs
	Turn-on time	t <sub>on</sub>		_	0.4	_	
	Fall time	t <sub>f</sub>		_	0.2	0.35	
	Turn-off time	t <sub>off</sub>		-	0.4	_	
Forward voltage		V <sub>F</sub>	I <sub>F</sub> = 10 A, V <sub>GE</sub> = 0 V	_	_	2.0	V
Reverse recovery time trr		t <sub>rr</sub>	I <sub>F</sub> = 10 A, di/dt = -100 A/µs	_	_	200	ns
Thermal resistance		R <sub>th (j-c)</sub>	Transistor	_	—	3.09	°C/W
			Diode	_	—	4.77	

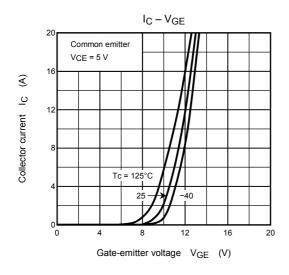
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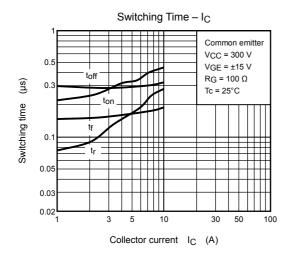


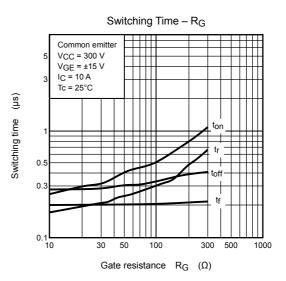


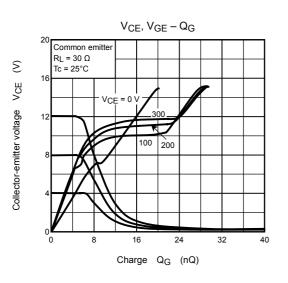


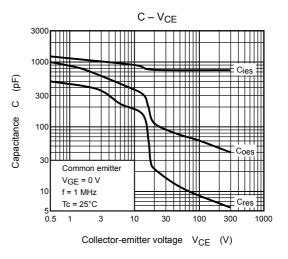


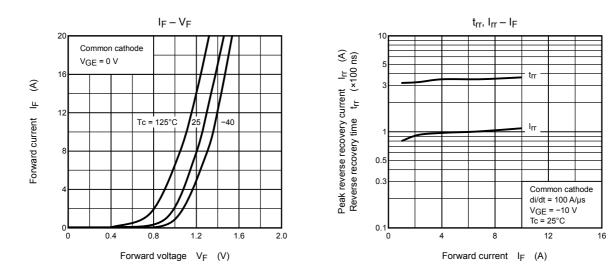
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Curves must be derated linearly with increase in temperature.

1

10

Collector-emitter voltage  $V_{CE}$  (V)

100

1000

0 0

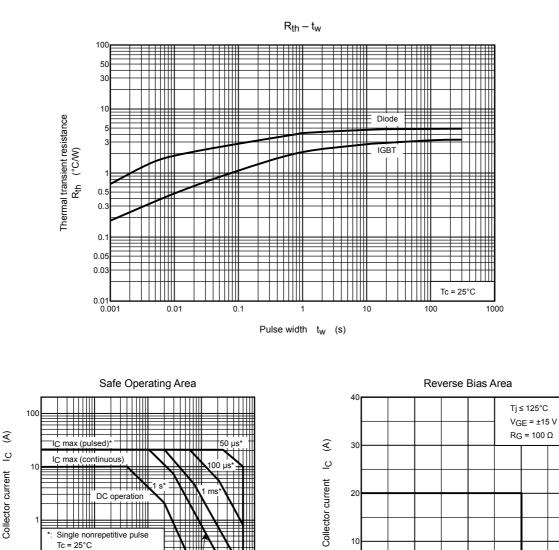
200

400

Collector-emitter voltage  $~V_{CE}~~(V)$ 

600

0.1 0.1



800

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